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Samsung Selects RFMD's PowerSmart(R) to Power Next-Generation GALAXY Note II

RFMD's Broad Product Portfolio Supporting Samsung Across All Product Tiers and Baseband Architectures

GREENSBORO, N.C., Sept. 5, 2012 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, announced today that it is enabling Samsung's next-generation GALAXY Note II with RFMD's PowerSmart® Power Platforms — the industry's first and only converged multimode, multiband (MMMB) power amplifiers.

Bob Bruggeworth, president and CEO of RFMD, said, "We are delighted to support Samsung's next-generation GALAXY Note II as well as numerous other flagship devices in Samsung's exciting product family. With the ramp of the GALAXY Note II, RFMD extends our coverage of Samsung's product portfolio to include all tiers and segments. In the coming months, we look forward to the availability of additional devices and baseband architectures that expand our business with Samsung to include additional PAs, incremental switch-based content, and new high-performance WiFi front ends."

The Samsung GALAXY Note II features a 5.5" HD Super AMOLED screen, providing breathtaking visuals and crystal clear detail. Its 16:9 screen ratio ensures an immersive and enriched cinema-like video viewing experience, perfect for watching HD videos on-the-go. The GALAXY Note II also comes with a mighty 1.6GHz Quad-Core processor and HSPA Plus or 4G LTE connectivity to deliver easy multitasking, lightning-fast screen transitions, powerful browser performance, and minimal app load time. In addition, it has an 8 megapixel rear-facing camera and 1.9 megapixel front-facing camera with HD video recording capabilities. The Samsung GALAXY Note II is set to launch in October starting in major European, Asian, and Middle East markets.

RFMD enables Samsung with a broad range of 3G/4G front end solutions, including PowerSmart, RFMD's ultra-high efficiency 3G/4G power amplifiers, RFMD's high performance switches, and RFMD's advanced power management solutions. RFMD supports Samsung across all leading baseband architectures, and RFMD's broad product portfolio provides Samsung full coverage across all major product categories.

RFMD's PowerSmart power platforms deliver industry-leading integration, design flexibility, and customization, enabling smartphone manufacturers to rapidly deploy smartphone platforms across geographies and networks, regardless of mode or band specifications.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the mobile device, wireless infrastructure, wireless local area network (WLAN or WiFi), cable television (CATV)/broadband, Smart Energy/advanced metering infrastructure (AMI), and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001-, ISO 14001-, and ISO/TS 16949-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements,

other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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